



PRODUCT NAME : Q6015L5 15A 600V TRI
AC

PRICE : Rs 35.00

SKU : RM2005



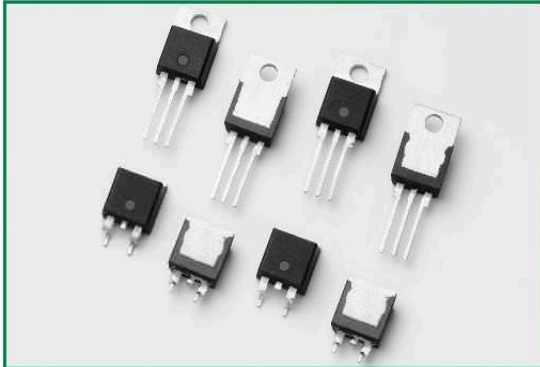
DESCRIPTION

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Teccor® brand Thyristors
 15 Amp Standard & 16 Amp Alternistor (High Commutation) Triacs



RoHS Qxx15xx & Qxx16xHx Series



Description

15 Amp and 16 Amp bi-directional solid state switch series is designed for AC switching and phase control applications such as motor speed and temperature modulation controls, lighting controls, and static switching relays.

Standard type devices normally operate in Quadrants I & III triggered from AC line.

Alternistor type devices only operate in quadrants I, II, & III and are used in circuits requiring high dv/dt capability.

Features & Benefits

- RoHS Compliant
- Glass – passivated junctions
- Voltage capability up to 1000 V
- Surge capability up to 200 A
- Electrically isolated “L-Package” is UL recognized for 2500Vrms
- Solid-state switching eliminates arcing or contact bounce that create voltage transients
- No contacts to wear out from reaction of switching events
- Restricted (or limited) RFI generation, depending on activation point in sine wave
- Requires only a small gate activation pulse in each half-cycle

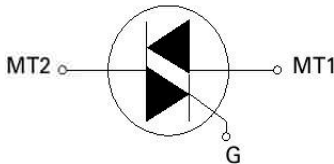
Agency Approval

Agency	Agency File Number
	L Package : E71639

Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	15 & 16	A
V_{DRM}/V_{RRM}	400 to 1000	V
$I_{GT(IQ1)}$	10 to 80	mA

Schematic Symbol



Applications

Excellent for AC switching and phase control applications such as heating, lighting, and motor speed controls.

Typical applications are AC solid-state switches, light dimmers, power tools, lawn care equipment, home/brown goods and white goods appliances.

Alternistor Triacs (no snubber required) are used in applications with extremely inductive loads requiring highest commutation performance.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

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Absolute Maximum Ratings — Standard Triac

Symbol	Parameter	Value	Unit	
$I_{T(RMS)}$	RMS on-state current (full sine wave)	Qxx15Ly $T_c = 80^\circ\text{C}$	15	A
		Qxx15Ry Qxx15Ny $T_c = 90^\circ\text{C}$		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_J initial = 25°C)	f = 50 Hz t = 20 ms	167	A
		f = 60 Hz t = 16.7 ms	200	
I^2t	I^2t Value for fusing	$t_p = 8.3$ ms	166	A^2s
di/dt	Critical rate of rise of on-state current	f = 120 Hz $T_J = 125^\circ\text{C}$	100	$\text{A}/\mu\text{s}$
I_{GTM}	Peak gate trigger current	$t_p \leq 10 \mu\text{s}$ $I_{GT} \leq I_{GTM}$ $T_J = 125^\circ\text{C}$	2.0	A
$P_{G(AV)}$	Average gate power dissipation	$T_J = 125^\circ\text{C}$	0.5	W
T_{stg}	Storage temperature range		-40 to 150	$^\circ\text{C}$
T_J	Operating junction temperature range		-40 to 125	$^\circ\text{C}$

Note: xx = voltage, y = sensitivity

Absolute Maximum Ratings — Alternistor Triac (3 Quadrants)

Symbol	Parameter	Value	Unit	
$I_{T(RMS)}$	RMS on-state current (full sine wave)	Qxx16LHy $T_c = 80^\circ\text{C}$	16	A
		Qxx16RHy Qxx16NHy $T_c = 90^\circ\text{C}$		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_J initial = 25°C)	f = 50 Hz t = 20 ms	167	A
		f = 60 Hz t = 16.7 ms	200	
I^2t	I^2t Value for fusing	$t_p = 8.3$ ms	166	A^2s
di/dt	Critical rate of rise of on-state current	f = 120 Hz $T_J = 125^\circ\text{C}$	100	$\text{A}/\mu\text{s}$
I_{GTM}	Peak gate trigger current	$t_p \leq 10 \mu\text{s}$; $I_{GT} \leq I_{GTM}$ $T_J = 125^\circ\text{C}$	2.0	A
$P_{G(AV)}$	Average gate power dissipation	$T_J = 125^\circ\text{C}$	0.5	W
T_{stg}	Storage temperature range		-40 to 150	$^\circ\text{C}$
T_J	Operating junction temperature range		-40 to 125	$^\circ\text{C}$

Note: xx = voltage, y = sensitivity

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified) — Standard Triac

Symbol	Test Conditions	Quadrant	Value	Unit	
I_{GT}	$V_D = 12\text{V}$ $R_L = 60 \Omega$	I – II – III	MAX.	50	mA
V_{GT}		I – II – III	MAX.	2.0	
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{k}\Omega$ $T_J = 125^\circ\text{C}$	I – II – III	MIN.	0.2	V
I_H	$I_T = 100\text{mA}$		MAX.	70	mA
dv/dt	$V_D = V_{DRM}$ Gate Open $T_J = 125^\circ\text{C}$	400V	MIN.	275	V/ μs
		600V		225	
		800V		200	
	$V_D = V_{DRM}$ Gate Open $T_J = 100^\circ\text{C}$	1000V		200	
$(dv/dt)_c$	$(di/dt)_c = 8.1 \text{A/ms}$ $T_J = 125^\circ\text{C}$		MIN.	4	V/ μs
t_{gr}	$I_G = 2 \times I_{GT}$ $PW = 15\mu\text{s}$ $I_T = 22.6 \text{A(pk)}$		TYP.	4	μs

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Electrical Characteristics (T_J = 25°C, unless otherwise specified) — Alternistor Triac (3 Quadrants)

Symbol	Test Conditions	Quadrant	Qxx16xH2	Qxx16xH3	Qxx16xH4	Qxx16xH6	Unit	
I _{GT}	V _D = 12V R _L = 60 Ω	I – II – III	MAX.	10	20	35	80	mA
V _{GT}		I – II – III	MAX.	1.3				V
V _{GD}	V _D = V _{DRM} R _L = 3.3 kΩ T _J = 125°C	I – II – III	MIN.	0.2				V
I _H	I _T = 100mA		MAX.	15	35	50	70	mA
dv/dt	V _D = V _{DRM} Gate Open T _J = 125°C	400V	MIN.	200	350	475	925	V/μs
		600V		150	250	400	850	
		800V		100	200	350	475	
	V _D = V _{DRM} Gate Open T _J = 100°C	1000V		100	200	300	350	
(dv/dt) _c	(di/dt) _c = 8.6 A/ms T _J = 125°C		MIN.	2	20	25	30	V/μs
t _{gt}	I _G = 2 x I _{GT} PW = 15μs I _T = 22.6 A(pk)		TYP.	3	3	3	5	μs

Static Characteristics

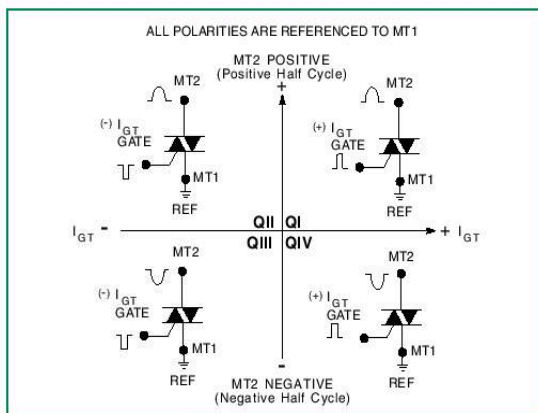
Symbol	Test Conditions	Value	Unit
V _{TM}	15A Device I _T = 21.2A t ₀ = 380μs	MAX	1.60
	16A Device I _T = 22.6A t ₀ = 380μs		
I _{DRM} I _{RRM}	V _D = V _{DRM} / V _{RRM}	T _J = 25°C 400-1000V	5
		T _J = 125°C 400-800V	2
		T _J = 100°C 1000V	3

Thermal Resistances

Symbol	Parameter	Value	Unit
R _{θ(J-C)}	Junction to case (AC)	Qxx15Ry Qxx15Ny Qxx16RH _y Qxx16NH _y	1.1
		Qxx15Ly Qxx16LH _y	2.1
R _{θ(J-A)}	Junction to ambient	Qxx15Ry Qxx16RH _y	45
		Qxx15Ly Qxx16LH _y	50

Note: xx = voltage; y = sensitivity

Figure 1: Definition of Quadrants



Note: Alternistors will not operate in QIV

Figure 2: Normalized DC Gate Trigger Current for All Quadrants vs. Junction Temperature

